# R6025FNZ

**Nch 600V 25A Power MOSFET** Datasheet

| | |
|---|---|
| $V_{DSS}$ | 600V |
| $R_{DS(on)}$ (Max.) | 0.18Ω |
| $I_D$ | 25A |
| $P_D$ | 150W |

## ●Outline

TO-3PF


## ●Features

1) Low on-resistance.

2) Fast switching speed.

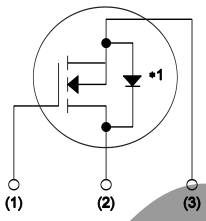
3) Gate-source voltage ($V_{GSS}$) guaranteed to be ±30V.

4) Drive circuits can be simple.

5) Parallel use is easy.

6) Pb-free lead plating ; RoHS compliant

## ●Inner circuit




(1) Gate
(2) Drain
(3) Source

*1 BODY DIODE

## ●Application

Switching Power Supply

## ●Packaging specifications

| | | |
|---|---|---|
| Type | Packaging | Tube |
| | Reel size (mm) | - |
| | Tape width (mm) | - |
| | Basic ordering unit (pcs) | 360 |
| | Taping code | C8 |
| | Marking | R6025FNZ |

## ●Absolute maximum ratings($T_a$ = 25°C)

| Parameter | | Symbol | Value | Unit |
|---|---|---|---|---|
| Drain - Source voltage | | $V_{DSS}$ | 600 | V |
| Continuous drain current | $T_c$ = 25°C | $I_D$ *1 | ±25 | A |
| | $T_c$ = 100°C | $I_D$ *1 | ±12 | A |
| Pulsed drain current | | $I_{D,pulse}$ *2 | ±100 | A |
| Gate - Source voltage | | $V_{GSS}$ | ±30 | V |
| Avalanche energy, single pulse | | $E_{AS}$ *3 | 42.1 | mJ |
| Avalanche energy, repetitive | | $E_{AR}$ *4 | 9.7 | mJ |
| Avalanche current | | $I_{AR}$ *3 | 12.5 | A |
| Power dissipation ($T_c$ = 25°C) | | $P_D$ | 150 | W |
| Junction temperature | | $T_j$ | 150 | °C |
| Range of storage temperature | | $T_{stg}$ | −55 to +150 | °C |
| Reverse diode dv/dt | | dv/dt *5 | 15 | V/ns |

## ●Absolute maximum ratings

| Parameter | Symbol | Conditions | Values | Unit |
|---|---|---|---|---|
| Drain - Source voltage slope | dv/dt | $V_{DS}$ = 480V, $I_D$ = 25A<br>$T_j$ = 125°C | 50 | V/ns |

## ●Thermal resistance

| Parameter | Symbol | Values | | | Unit |
|---|---|---|---|---|---|
| | | Min. | Typ. | Max. | |
| Thermal resistance, junction - case | $R_{thJC}$ | - | - | 0.83 | °C/W |
| Thermal resistance, junction - ambient | $R_{thJA}$ | - | - | 40 | °C/W |
| Soldering temperature, wavesoldering for 10s | $T_{sold}$ | - | - | 265 | °C |

## ●Electrical characteristics($T_a$ = 25°C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|---|---|---|---|---|---|---|
| | | | Min. | Typ. | Max. | |
| Drain - Source breakdown voltage | $V_{(BR)DSS}$ | $V_{GS}$ = 0V, $I_D$ = 1mA | 600 | - | - | V |
| Drain - Source avalanche breakdown voltage | $V_{(BR)DS}$ | $V_{GS}$ = 0V, $I_D$ = 12.5A | - | 700 | - | V |
| Zero gate voltage drain current | $I_{DSS}$ | $V_{DS}$ = 600V, $V_{GS}$ = 0V<br>$T_j$ = 25°C | - | 0.1 | 100 | μA |
| | | $T_j$ = 125°C | - | - | 100 | mA |
| Gate - Source leakage current | $I_{GSS}$ | $V_{GS}$ = ±30V, $V_{DS}$ = 0V | - | - | ±100 | nA |
| Gate threshold voltage | $V_{GS\ (th)}$ | $V_{DS}$ = 10V, $I_D$ = 1mA | 3 | - | 5 | V |
| Static drain - source on - state resistance | $R_{DS(on)}$ *6 | $V_{GS}$ = 10V, $I_D$ = 12.5A<br>$T_j$ = 25°C | - | 0.14 | 0.18 | Ω |
| | | $T_j$ = 125°C | - | 0.28 | - | |
| Gate input resistance | $R_G$ | f = 1MHz, open drain | - | 3.3 | - | Ω |

●**Electrical characteristics**($T_a$ = 25°C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|---|---|---|---|---|---|---|
| | | | Min. | Typ. | Max. | |
| Transconductance | $g_{fs}$ *6 | $V_{DS}$ = 10V, $I_D$ = 12.5A | 9 | 18 | - | S |
| Input capacitance | $C_{iss}$ | $V_{GS}$ = 0V | - | 3500 | - | pF |
| Output capacitance | $C_{oss}$ | $V_{DS}$ = 25V | - | 2200 | - | |
| Reverse transfer capacitance | $C_{rss}$ | f = 1MHz | - | 45 | - | |
| Effective output capacitance, energy related | $C_{o(er)}$ | $V_{GS}$ = 0V<br>$V_{DS}$ = 0V ~ 480V | - | 111 | - | pF |
| Effective output capacitance, time related | $C_{o(tr)}$ | | - | 364 | - | |
| Turn - on delay time | $t_{d(on)}$ *6 | $V_{DD}$ ≃ 300V, $V_{GS}$ = 10V | - | 57 | - | ns |
| Rise time | $t_r$ *6 | $I_D$ = 12.5A | - | 115 | - | |
| Turn - off delay time | $t_{d(off)}$ *6 | $R_L$ = 24Ω | - | 150 | 300 | |
| Fall time | $t_f$ *6 | $R_G$ = 10Ω | - | 72 | 144 | |

●**Gate Charge characteristics**($T_a$ = 25°C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|---|---|---|---|---|---|---|
| | | | Min. | Typ. | Max. | |
| Total gate charge | $Q_g$ *6 | $V_{DD}$ ≃ 300V | - | 85 | - | nC |
| Gate - Source charge | $Q_{gs}$ *6 | $I_D$ = 25A | - | 25 | - | |
| Gate - Drain charge | $Q_{gd}$ *6 | $V_{GS}$ = 10V | - | 35 | - | |
| Gate plateau voltage | $V_{(plateau)}$ | $V_{DD}$ ≃ 300V, $I_D$ = 25A | - | 7.1 | - | V |

*1 Limited only by maximum temperature allowed.

*2 $P_W \leq 10\mu s$, Duty cycle ≤ 1%

*3 L ≃ 500μH, $V_{DD}$ = 50V, $R_G$ = 25Ω, starting $T_j$ = 25°C

*4 L ≃ 500μH, $V_{DD}$ = 50V, $R_G$ = 25Ω, starting $T_j$ = 25°C, f = 10kHz

*5 Reference measurement circuits Fig.5-1.

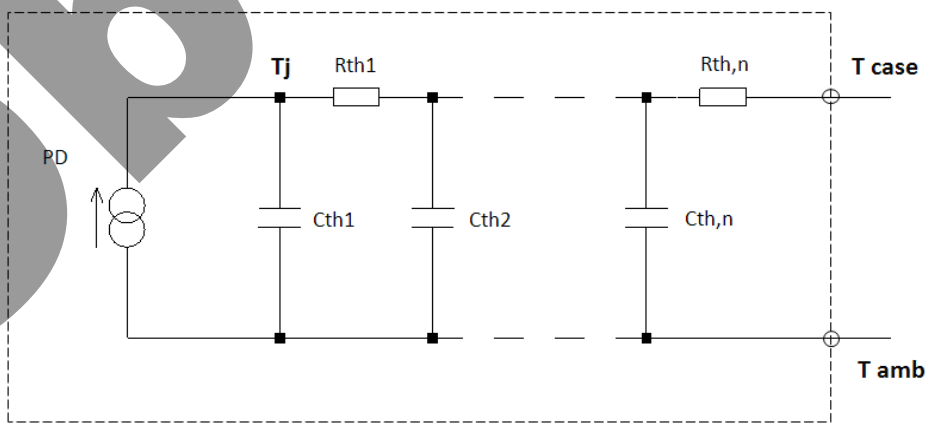
*6 Pulsed

## ●Body diode electrical characteristics (Source-Drain)($T_a$ = 25°C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|---|---|---|---|---|---|---|
| | | | Min. | Typ. | Max. | |
| Inverse diode continuous, forward current | $I_S$ *1 | $T_c$ = 25°C | - | - | 25 | A |
| Inverse diode direct current, pulsed | $I_{SM}$ *2 | | - | - | 100 | A |
| Forward voltage | $V_{SD}$ *6 | $V_{GS}$ = 0V, $I_S$ = 25A | - | - | 1.5 | V |
| Reverse recovery time | $t_{rr}$ *6 | $I_S$ = 25A<br>di/dt = 100A/μs | - | 120 | - | ns |
| Reverse recovery charge | $Q_{rr}$ *6 | | - | 0.53 | - | μC |
| Peak reverse recovery current | $I_{rrm}$ *6 | | - | 9 | - | A |
| Peak rate of fall of reverse recovery current | $di_{rr}/dt$ | $T_j$ = 25°C | - | 1150 | - | A/μs |

## ●Typical Transient Thermal Characteristics

| Symbol | Value | Unit | Symbol | Value | Unit |
|---|---|---|---|---|---|
| $R_{th1}$ | 0.0564 | K/W | $C_{th1}$ | 0.0077 | Ws/K |
| $R_{th2}$ | 0.391 | | $C_{th2}$ | 0.0779 | |
| $R_{th3}$ | 1.26 | | $C_{th3}$ | 1.13 | |



## ●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

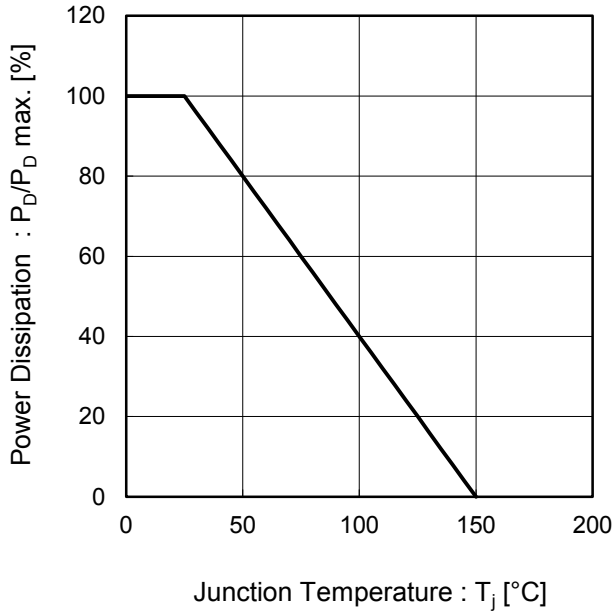



Fig.2 Maximum Safe Operating Area

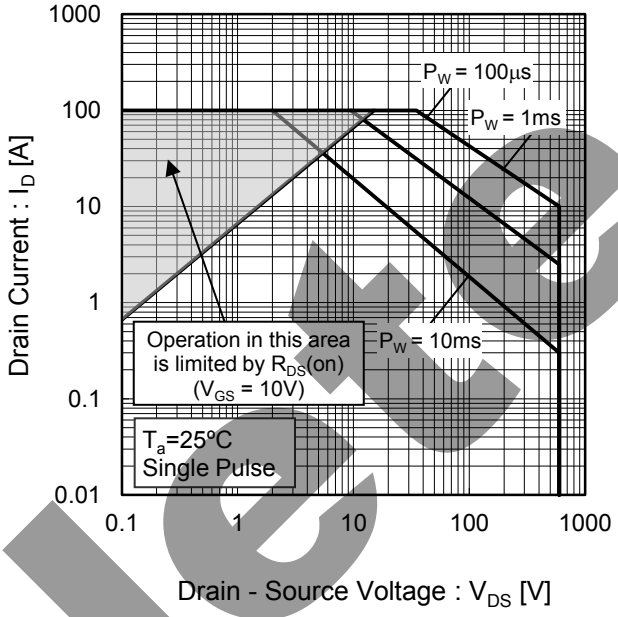
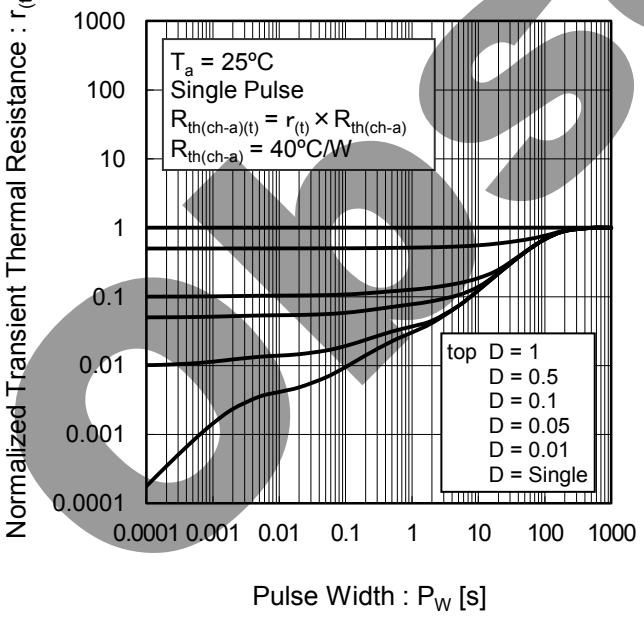



Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



## ●Electrical characteristic curves

Fig.4 Avalanche Current vs Inductive Load

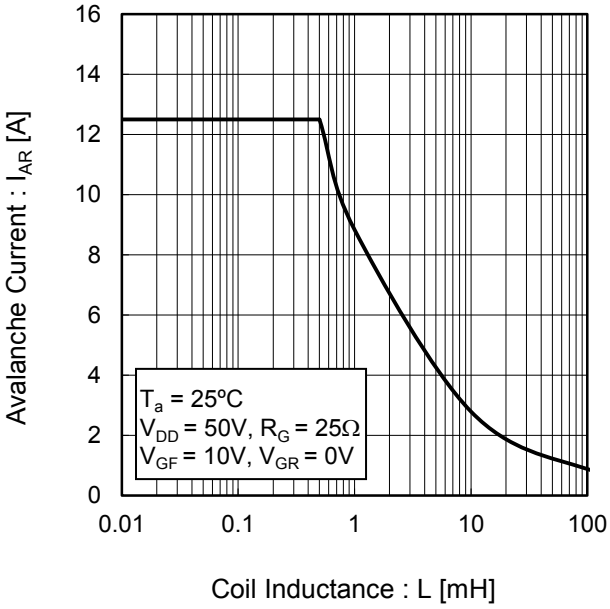



Fig.5 Avalanche Power Losses

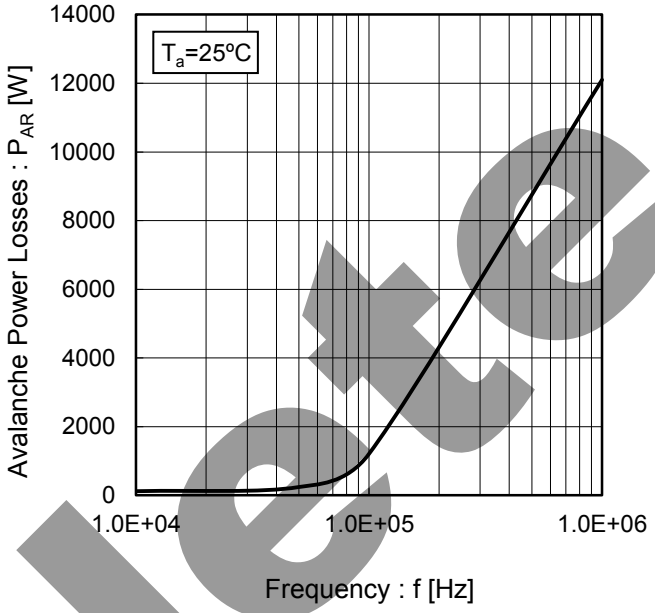
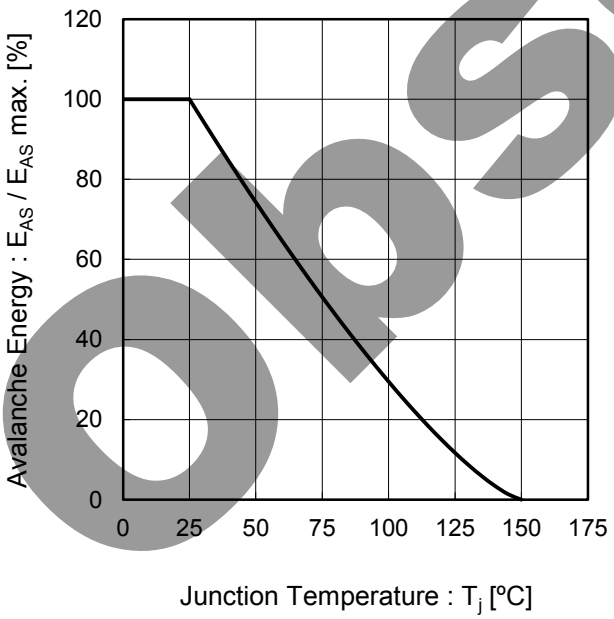



Fig.6 Avalanche Energy Derating Curve vs Junction Temperature



## ●Electrical characteristic curves

Fig.7 Typical Output Characteristics(I)

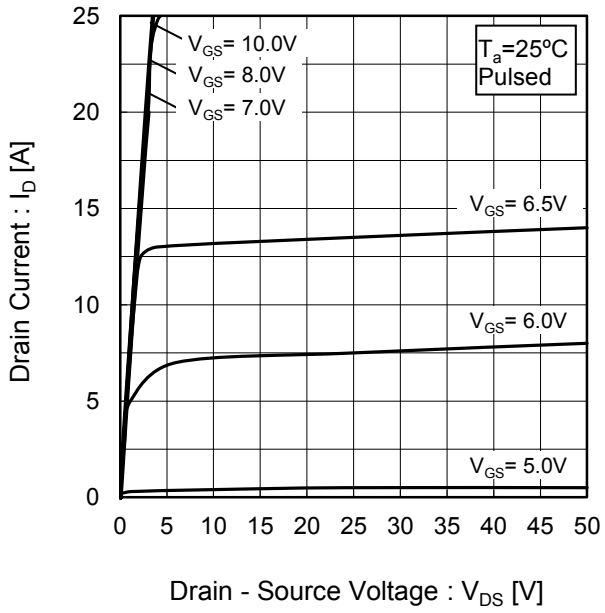



Fig.8 Typical Output Characteristics(II)

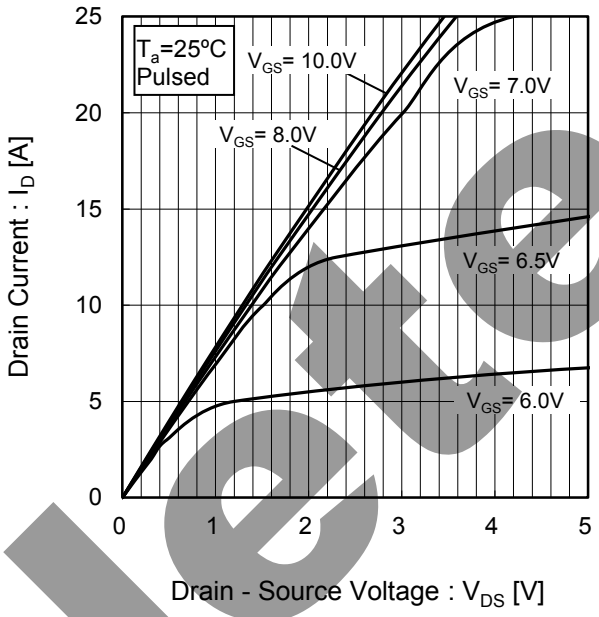



Fig.9 $T_j$ = 150°C Typical Output Characteristics(I)

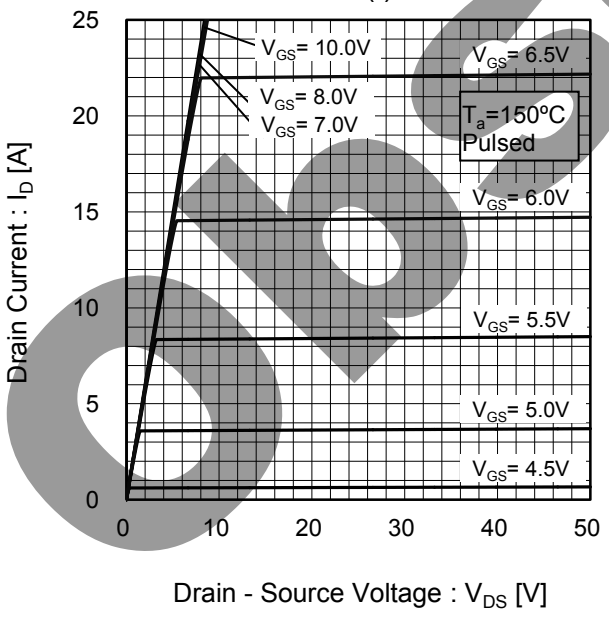
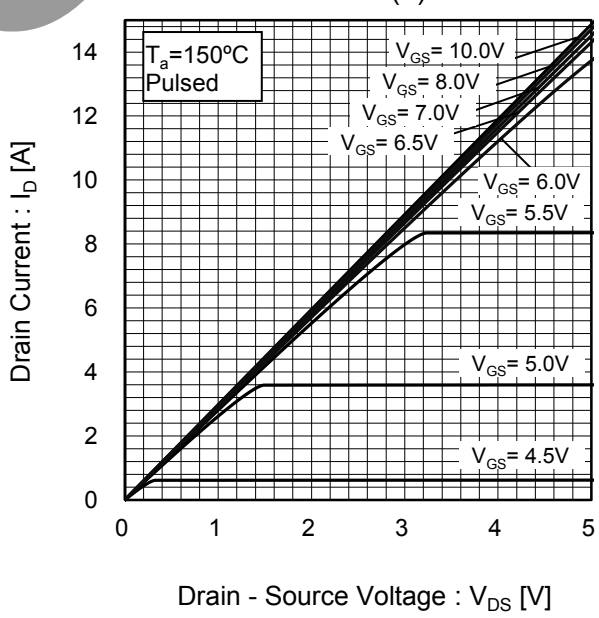



Fig.10 $T_j$ = 150°C Typical Output Characteristics(II)



## ●Electrical characteristic curves

Fig.11 Breakdown Voltage vs. Junction Temperature

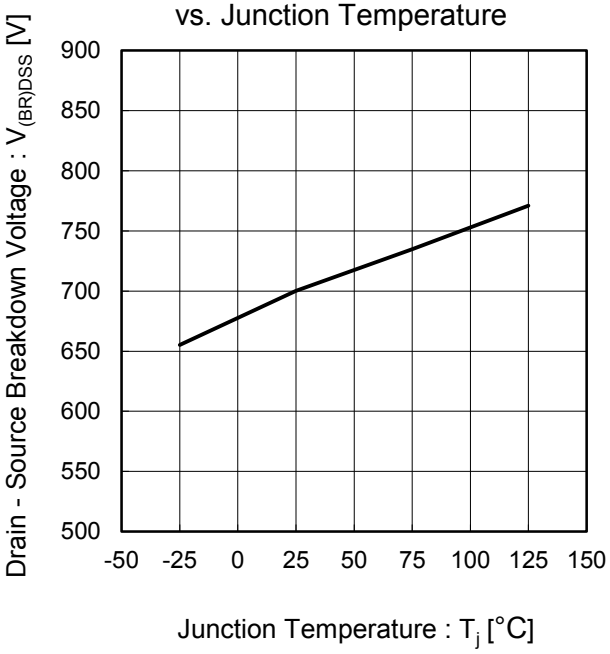



Fig.12 Typical Transfer Characteristics

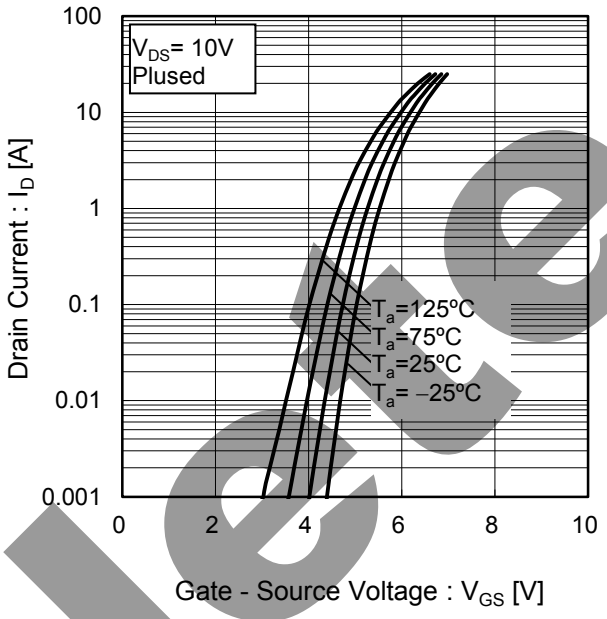



Fig.13 Gate Threshold Voltage vs. Junction Temperature

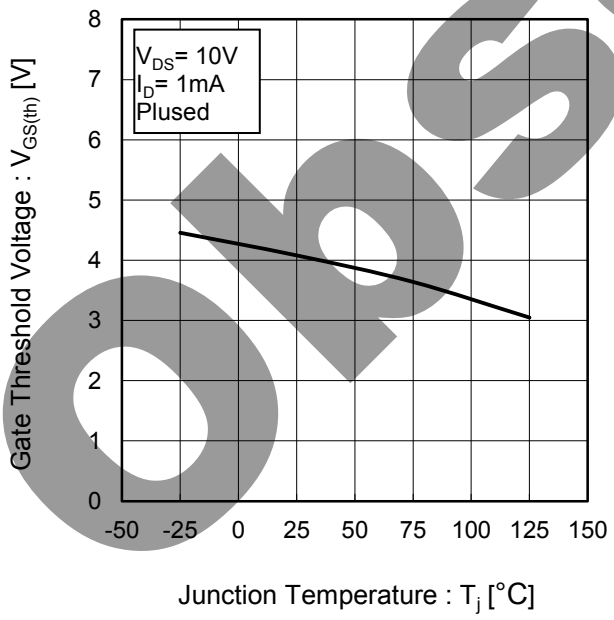
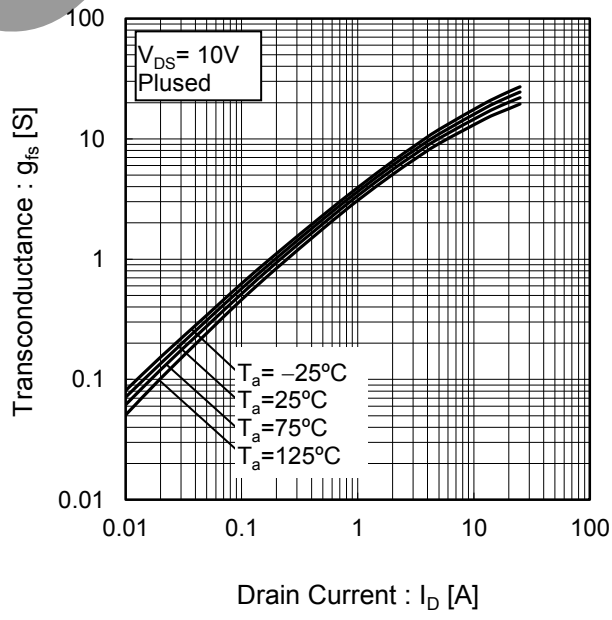



Fig.14 Transconductance vs. Drain Current



## ●Electrical characteristic curves

Fig.15 Static Drain - Source On - State Resistance vs. Gate Source Voltage

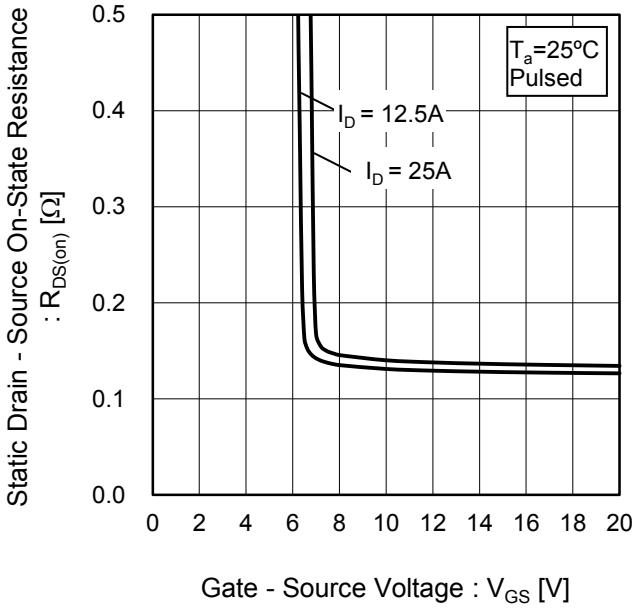



Fig.16 Static Drain - Source On - State Resistance vs. Junction Temperature

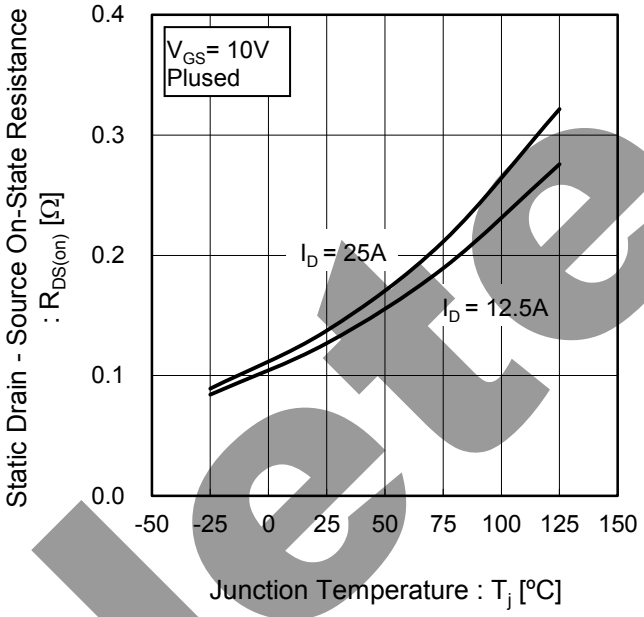
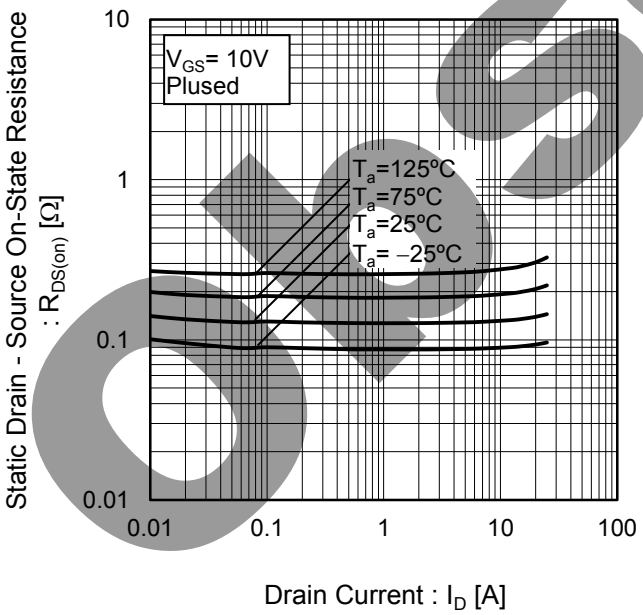



Fig.17 Static Drain - Source On - State Resistance vs. Drain Current



## ●Electrical characteristic curves

Fig.18 Typical Capacitance vs. Drain - Source Voltage

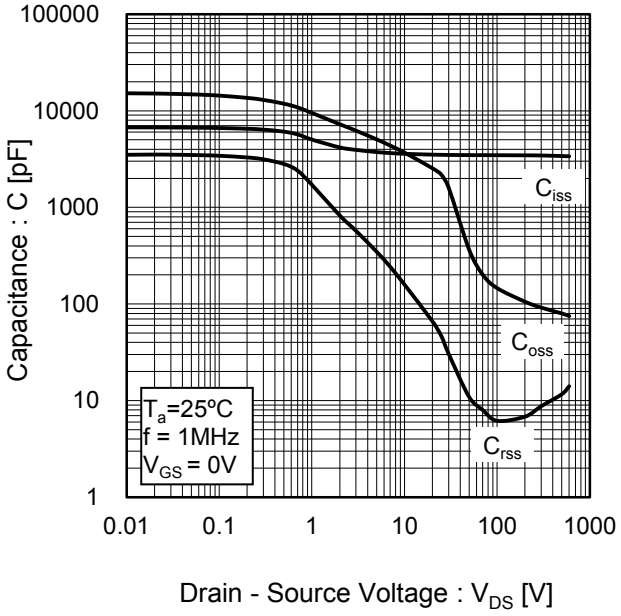



Fig.19 Coss Stored Energy

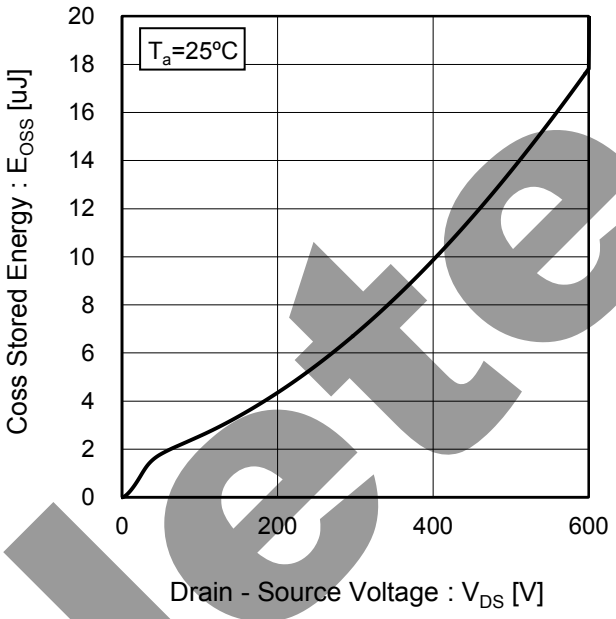



Fig.20 Switching Characteristics

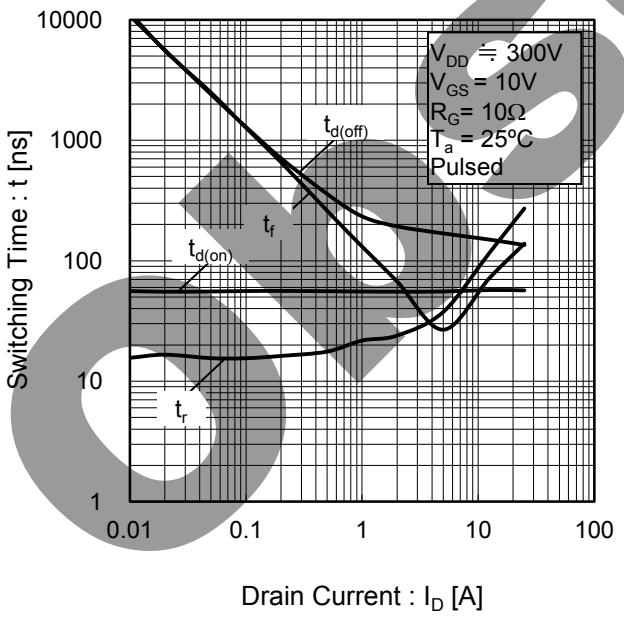
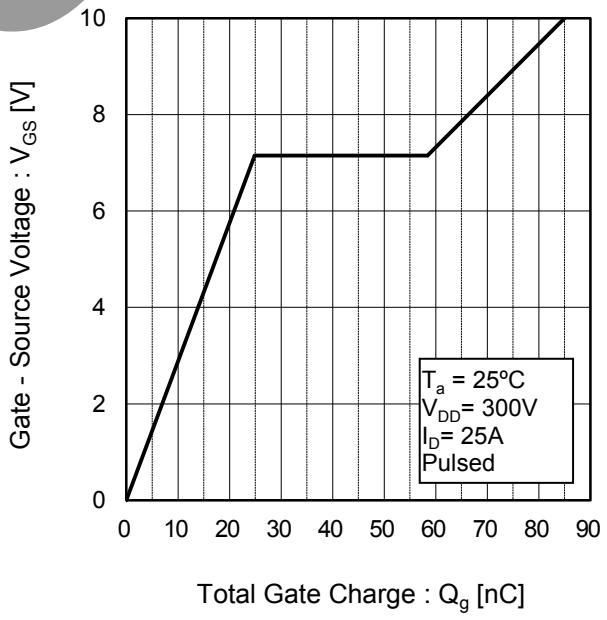



Fig.21 Dynamic Input Characteristics



## ●Electrical characteristic curves

Fig.22 Inverse Diode Forward Current vs. Source - Drain Voltage

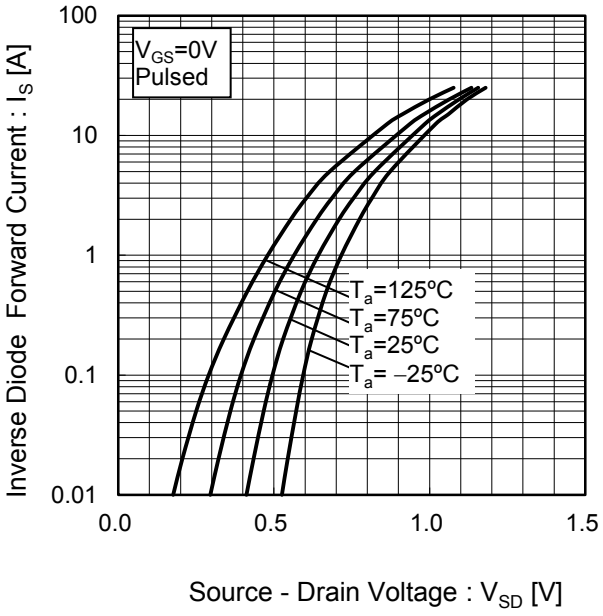
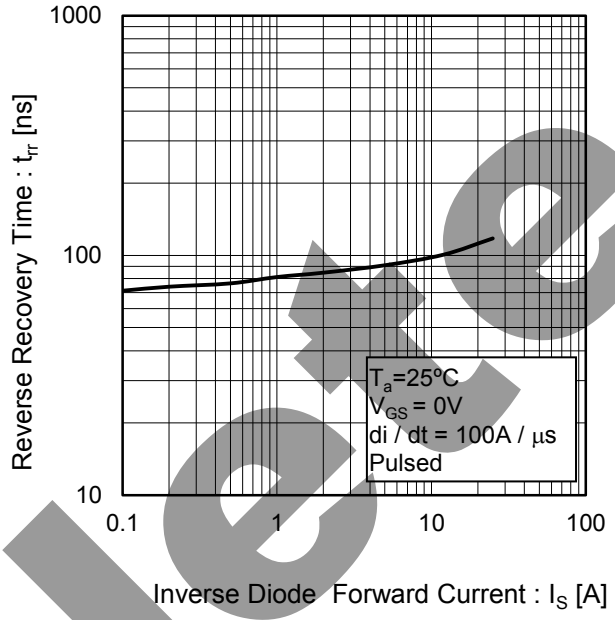



Fig.23 Reverse Recovery Time vs.Inverse Diode Forward Current



## ●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

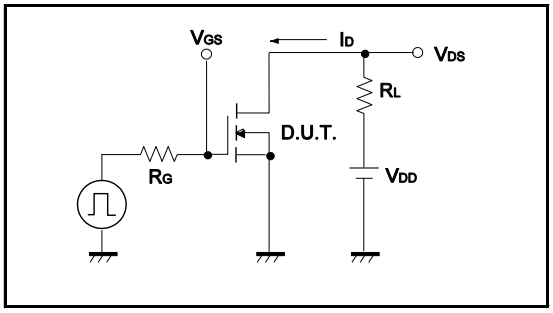



Fig.1-2 Switching Waveforms

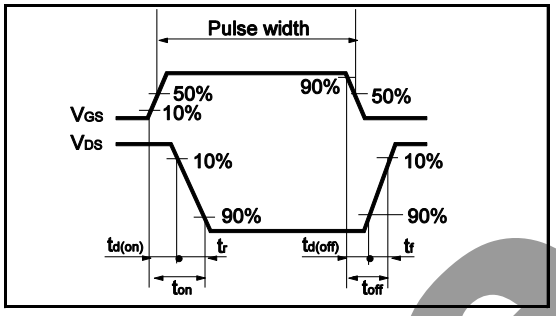



Fig.2-1 Gate Charge Measurement Circuit

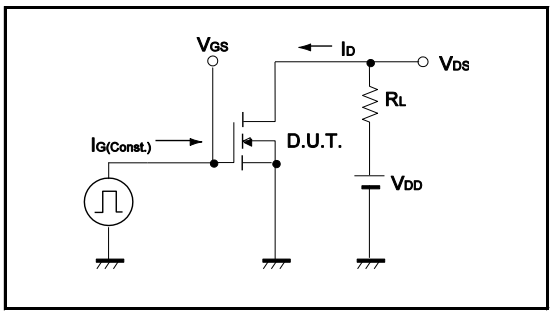



Fig.2-2 Gate Charge Waveform

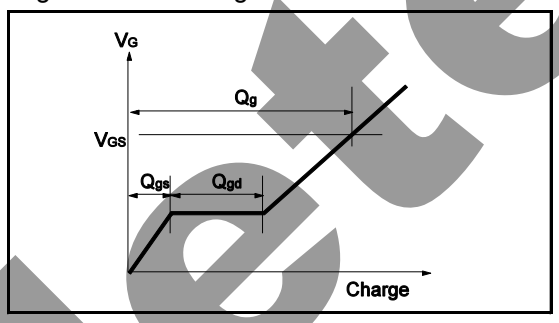



Fig.3-1 Avalanche Measurement Circuit

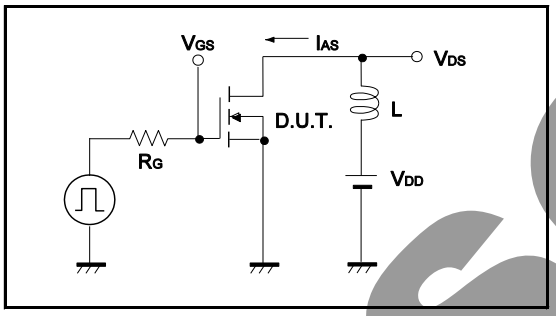



Fig.3-2 Avalanche Waveform

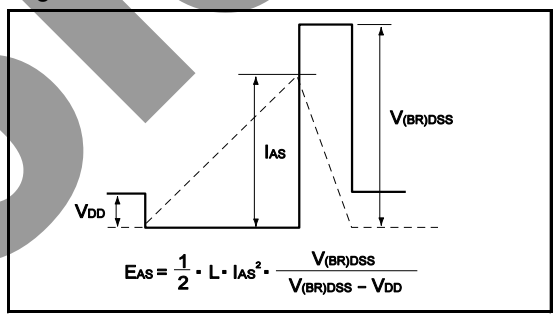



Fig.4-1 dv/dt Measurement Circuit

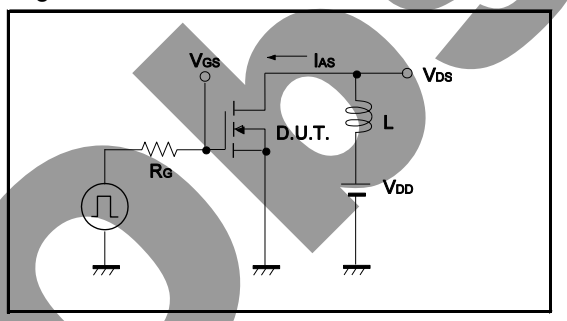



Fig.4-2 dv/dt Waveform

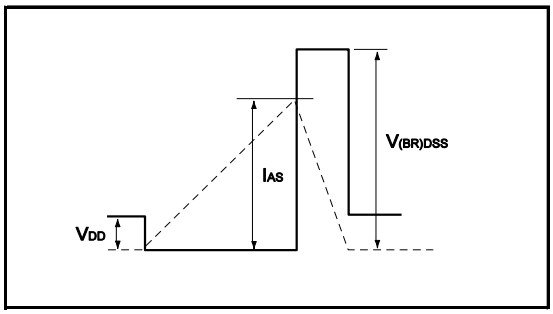



Fig.5-1 di/dt Measurement Circuit

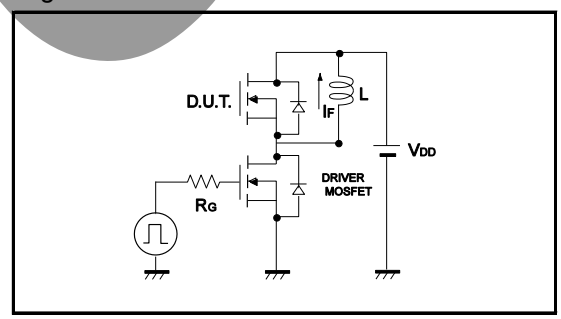
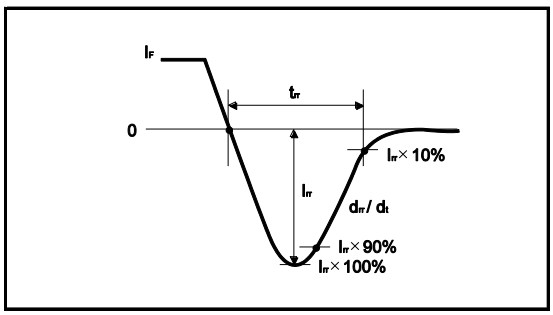
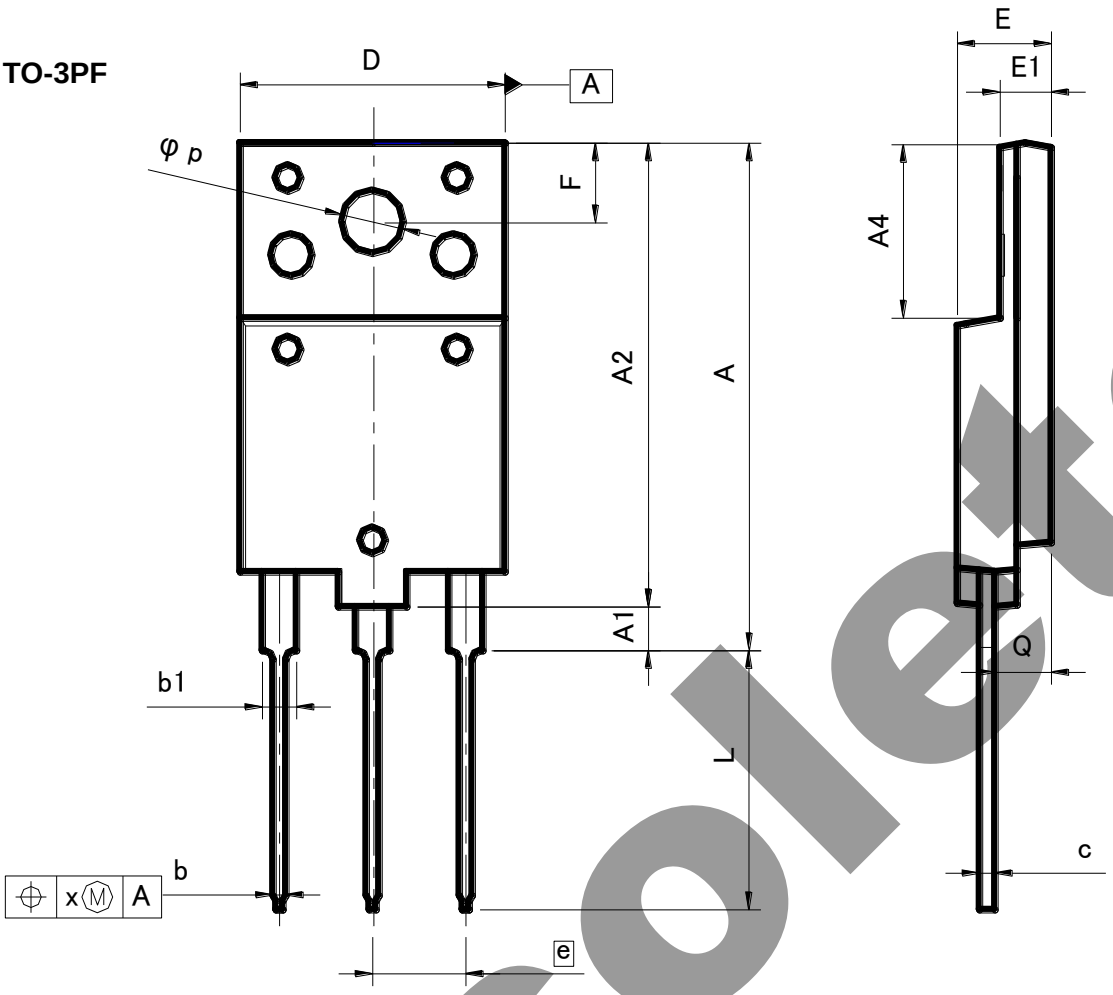



Fig.5-2 di/dt Waveform



●**Dimensions** (Unit : mm)

**TO-3PF**




| DIM | MILIMETERS | | INCHES | |
|---|---|---|---|---|
| | MIN | MAX | MIN | MAX |
| A | 26.30 | 26.70 | 1.035 | 1.051 |
| A1 | 2.30 | 2.70 | 0.091 | 0.106 |
| A2 | 26.30 | 26.70 | 1.035 | 1.051 |
| A4 | 9.80 | 10.20 | 0.386 | 0.402 |
| b | 0.65 | 0.95 | 0.026 | 0.037 |
| b1 | 1.80 | 2.20 | 0.071 | 0.087 |
| c | 0.80 | 1.10 | 0.031 | 0.043 |
| D | 15.30 | 15.70 | 0.602 | 0.618 |
| E | 5.30 | 5.70 | 0.209 | 0.224 |
| e | 5.45 | | 0.215 | – |
| E1 | 2.80 | 3.20 | 0.110 | 0.126 |
| F | 4.30 | 4.70 | 0.169 | 0.185 |
| L | 14.60 | 15.00 | 0.575 | 0.591 |
| p | 3.40 | 3.80 | 0.134 | 0.150 |
| Q | 3.10 | 3.50 | 0.122 | 0.138 |
| x | – | 0.50 | – | 0.020 |

Dimension in mm / inches

# Notice

## Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

| JAPAN | USA | EU | CHINA |
|---|---|---|---|
| CLASSⅢ | CLASSⅢ | CLASSⅡb | CLASSⅢ |
| CLASSⅣ | | CLASSⅢ | |

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
   [a] Installation of protection circuits or other protective devices to improve system safety
   [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
   [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
   [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
   [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including $Cl_2$, $H_2S$, $NH_3$, $SO_2$, and $NO_2$
   [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
   [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
   [f] Sealing or coating our Products with resin or other coating materials
   [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.) ; or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
   [h] Use of the Products in places subject to dew condensation

4. The Products are not subject to radiation-proof design.

5. Please verify and confirm characteristics of the final or mounted products in using the Products.

6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.

8. Confirm that operation temperature is within the specified range described in the product specification.

9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

## Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

### Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

### Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

### Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
   [a] the Products are exposed to sea winds or corrosive gases, including $Cl_2$, $H_2S$, $NH_3$, $SO_2$, and $NO_2$
   [b] the temperature or humidity exceeds those recommended by ROHM
   [c] the Products are exposed to direct sunshine or condensation
   [d] the Products are exposed to high Electrostatic

2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

### Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

### Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

### Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

### Precaution Regarding Intellectual Property Rights

1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.

2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).

3. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the Products or the information contained in this document. Provided, however, that ROHM will not assert its intellectual property rights or other rights against you or your customers to the extent necessary to manufacture or sell products containing the Products, subject to the terms and conditions herein.

### Other Precaution

1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.

2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.

3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.

4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

## General Precaution

1. Before you use our Products, you are requested to carefully read this document and fully understand its contents. ROHM shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any ROHM's Products against warning, caution or note contained in this document.

2. All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.

3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate and/or error-free. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.